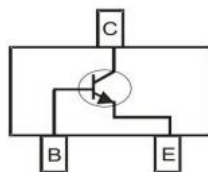


SOT-323 Bipolar Transistor 双极型三极管

■ Features 特点

NPN General Purpose 通用



■ Absolute Maximum Ratings 最大额定值

Characteristic 特性参数	Symbol 符号	BC817W- 16/25/40	BC818W- 16/25/40	Unit 单位
Collector-Base Voltage 集电极基极电压	V_{CBO}	50	30	V
Collector-Emitter Voltage 集电极发射极电压	V_{CEO}	45	25	V
Emitter-Base Voltage 发射极基极电压	V_{EBO}	5	5	V
Collector Current 集电极电流	I_C	500		mA
Power dissipation 耗散功率	$P_C(T_a=25^{\circ}\text{C})$	200		mW
Thermal Resistance Junction-Ambient 热阻	$R_{\theta JA}$	625		$^{\circ}\text{C}/\text{W}$
Junction and Storage Temperature 结温和储藏温度	T_J, T_{stg}	-55to+150 $^{\circ}\text{C}$		

■ Device Marking 产品打标

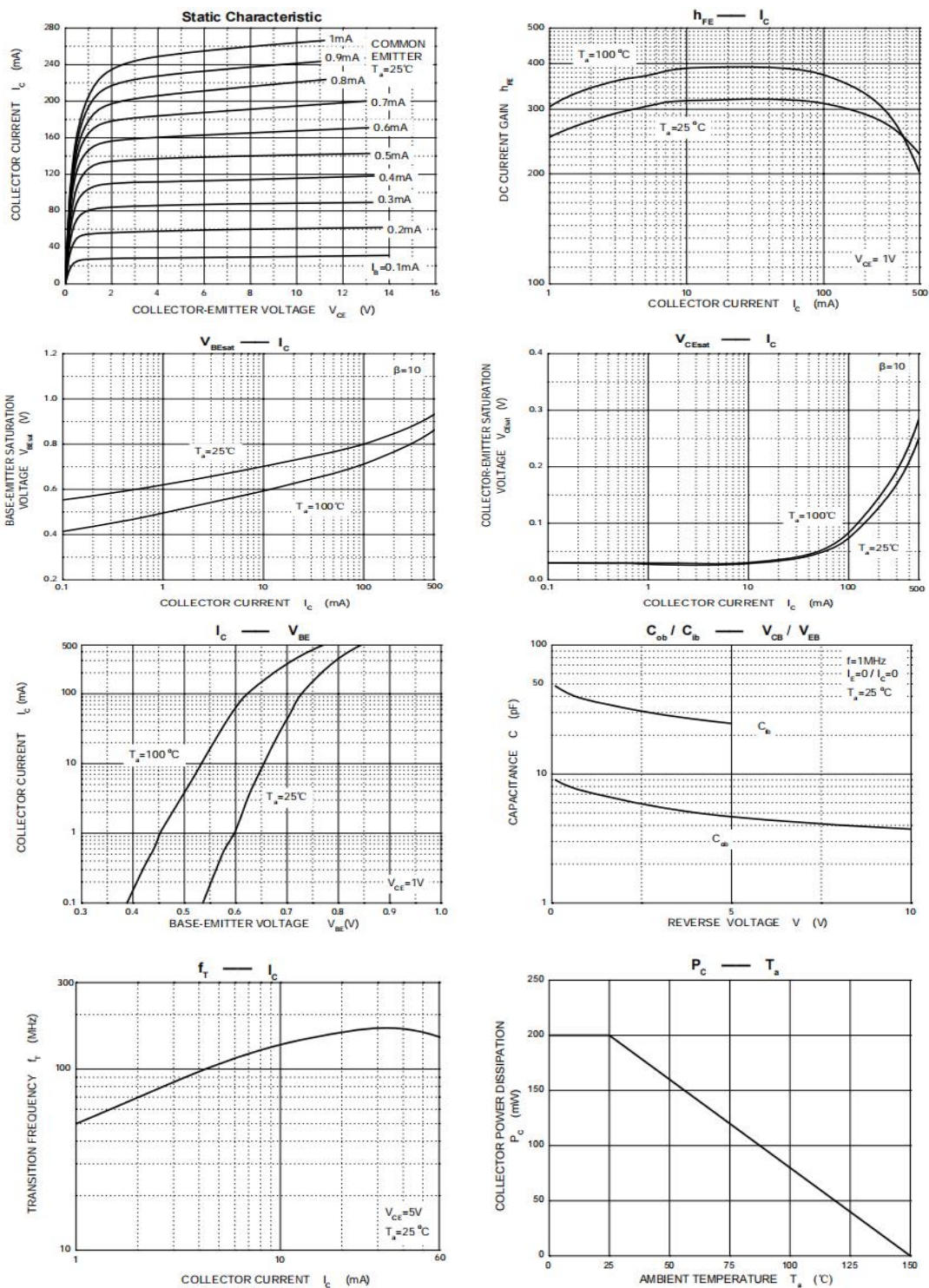
H_{FE}		100-250(-16)	160-400(-25)	250-600(-40)
Mark	BC817W	6A	6B	6C
	BC818W	6E	6F	6G

■Electrical Characteristics 电特性

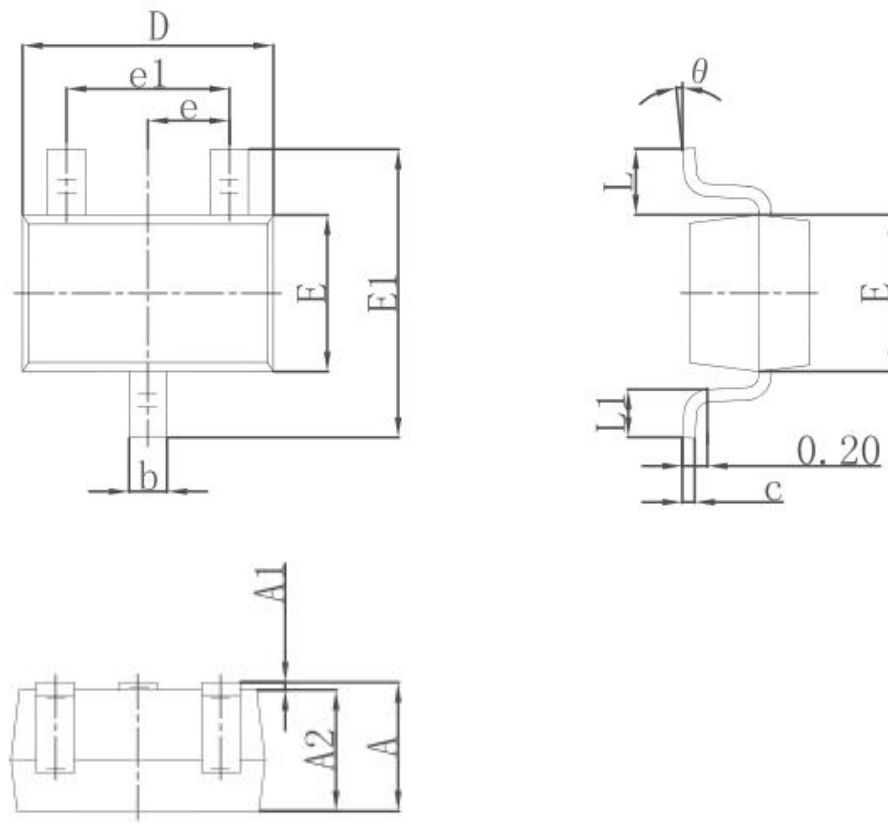
(TA=25℃ unless otherwise noted 如无特殊说明, 温度为 25℃)

Characteristic 特性参数		Symbol 符号	Min 最小值	Type 典型值	Max 最大值	Unit 单位
Collector-Base Breakdown Voltage 集电极基极击穿电压 (IC= 10μA, IE=0)	BC817W-16/25/40 BC818W-16/25/40	BV _{CBO}	50 30	—	—	V
Collector-Emitter Breakdown Voltage 集电极发射极击穿电压 (IC= 10mA, IB=0)	BC817W-16/25/40 BC818W-16/25/40	BV _{CEO}	45 25	—	—	V
Emitter-Base Breakdown Voltage 发射极基极击穿电压 (IE= 10μA, IC=0)		BV _{EBO}	5	—	—	V
Collector-Base Leakage Current 集电极基极漏电流	BC817W-16/25/40 (V _{CB} =50V,IE=0) BC818W-16/25/40 (V _{CB} =30V,IE=0)	IC _{BO}	—	—	100	nA
Emitter-Base Leakage Current 发射极基极漏电流 (V _{EB} =4V, IC=0)		IE _{BO}	—	—	100	nA
DC Current Gain 直流电流增益 (V _{CE} = 1V,IC= 100mA)	BC817W-16/BC818W-16 BC817W-25/BC818W-25 BC817W-40/BC818W-40	H _{FE}	100 160 250	—	250 400 600	
DC Current Gain 直流电流增益(V _{CE} = 1V,IC= 500mA)		H _{FE}	40			
Collector-Emitter Saturation Voltage 集电极发射极饱和压降(IC= 500mA, IB= 50mA)		V _{CE(sat)}	—	—	0.7	V
Base-Emitter Saturation Voltage 基极发射极饱和压降(IC= 500mA, IB= 50mA)		V _{BE(sat)}	—	—	1.2	V
Base-Emitter On Voltage 基极发射极导通电压(V _{CE} = 1V, IC= 500mA)		V _{BE(on)}	—	—	1.2	V
Transition Frequency 特征频率(V _{CE} = 5V, IC= 10mA)		f _T	100	—	—	MHz
Output Capacitance 输出电容(V _{CB} = 10V, IE=0, f=1MHz)		C _{ob}	—	10	—	pF

■ Typical Characteristic Curve 典型特性曲线



■Dimension 外形封装尺寸



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP		0.026 TYP	
e1	1.200	1.400	0.047	0.055
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°